

Form PTO-1449			ATTY. DOCKET NO. 3430-0200P			APPLICATION NO. NEW 10/757571				
INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)						APPLICANT Woong-Kwon KIM				
U.S. PATENT DOCUMENTS						FILED DATE January 15, 2003			GROUP Unassigned	
U.S. PATENT DOCUMENTS										
CLASSIFICATION INITIAL	DOCUMENT NUMBER	Kind	DATE	NAME	CLASS	SUB CLASS	FILED DATE IF APPROPRIATE			
09	US 5,994,721	A	1999-11-30	ZHONG et al						
	US 6,162,510	A	12-2000	KASHIWAZAKI et al						
	US 6,104,459	A	2000-08-15	OIKE et al						
	US 5,724,107	A	1998-03-03	NISHIKAWA et al						
	US 6,211,928	B1	2001-04-03	OH et al						
	US 6,221,543	B1	2001-04-24	GUEHLER et al						
	US 5,994,721	A	1999-11-30	ZHONG et al						
	US 6,162,510	A	2000-12-19	KASHIWAZAKI et al						
	US 6,297,862	B1	2001-10-02	MURADE						
	US 6,166,786	A	2000-12-26	OHKUBO et al						
a	US 6,327,006	B1	2001-12-04	SATO et al						
	US 6,281,955	B1	2001-08-28	MIDORIKAWA et al						
	US 6,111,623	A	2000-08-29	SATO						
FOREIGN PATENT DOCUMENTS										
Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO			
OTHER DOCUMENTS (Include name of the author (in CAPITAL LETTERS), title of the article (in appropriate), title of the item (book, journal, serial, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.										
a	Pichon et al; "Low temperature unhydrogenated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Vol. 296, pages 133-136, 1997.									
EXAMINER					DATE CONSIDERED					
Hoan Nguyen					8/31/04					
REMARKS: Initial if citation considered, changed or eliminated in its entirety with a.P.P. 600; show item through citation if not in entirety and not considered. Initial copy of this form with date of citation to applicant.										

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